NSN 5961-01-395-5851

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Inclosure Material:

Metal

Overall Length:

39.37 millimeters

Overall Height:

11.05 millimeters

Overall Width:

25.27 millimeters

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204ae

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1000.0 collector to emitter voltage, dc with base short-circuited to emitter

Current Rating Per Characteristic:

50.00 amperes collector current, dc

Power Rating Per Characteristic:

200.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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